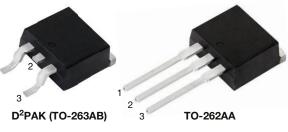
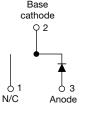
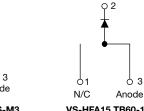


Vishay Semiconductors

HEXFRED[®], Ultrafast Soft Recovery Diode, 15 A







VS-HFA15 TB60S-M3

VS-HFA15 TB60-1-M3

PRIMARY CHARACTERISTICS						
I _{F(AV)}	15 A					
V _R	600 V					
V _F at I _F	1.2 V					
t _{rr} (typ.)	23 ns					
T _J max.	150 °C					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

FEATURES

- Ultrafast and ultrasoft recovery
- Very low I_{BBM} and Q_{rr}
- COMPLIANT • Meets MSL level 1, per J-STD-020, LF maximum HALOGEN peak of 245 °C FREE
- Designed and gualified for industrial level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

DESCRIPTION

VS-HFA15TB60S, VS-HFA15TB60-1 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the VS-HFA15TB60S, VS-HFA15TB60-1 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA15TB60S, VS-HFA15TB60-1 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Cathode to anode voltage	VR		600	V				
Maximum continuous forward current	I _F	T _C = 100 °C	15					
Single pulse forward current	I _{FSM}		150	А				
Maximum repetitive forward current	I _{FRM}		60					
Maximum neuror dissinction	PD	T _C = 25 °C	74	W				
Maximum power dissipation		T _C = 100 °C	29	1 VV				
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C				

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Document Number: 96313

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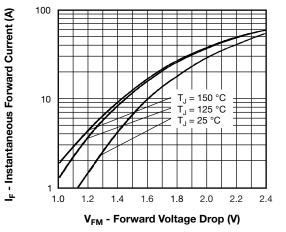
ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		600	-	-			
		I _F = 15 A		-	1.3	1.7	V		
Maximum forward voltage	V _{FM}	I _F = 30 A	See fig. 1	-	1.5	2.0			
		I _F = 15 A, T _J = 125 °C		-	1.2	1.6			
Maximum reverse	1	$V_{R} = V_{R}$ rated	See fig. 2	-	1.0	10			
leakage current	I _{RM}	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	See lig. 2	-	400	1000	μA		
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	25	50	pF		
Series inductance	L _S	Measured lead to lead 5 mm from pa	ackage body	-	8.0	-	nH		

DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ /}$	A/μs, V _R = 30 V	-	23	-			
Reverse recovery time See fig. 5	t _{rr1}	T _J = 25 °C		-	50	60	ns		
Occ lig. o	t _{rr2}	T _J = 125 °C		-	105	120			
Peak recovery current	I _{RRM1}	T _J = 25 °C	I _F = 15 A	-	4.5	6.0	Α		
See fig. 6	I _{RRM2}	T _J = 125 °C		-	6.5	10	A		
Reverse recovery charge	Q _{rr1}	T _J = 25 °C	dl _F /dt = 200 A/µs V _B = 200 V	-	84	180	nC		
See fig. 7	Q _{rr2}	T _J = 125 °C	$v_{\rm R} = 200 v$	-	241	600	nc		
Peak rate of fall of recovery current during t _b See fig. 8	dl _{(rec)M} /dt1	T _J = 25 °C		-	188	-			
	dl _{(rec)M} /dt2	T _J = 125 °C		-	160	-	A∕µs		

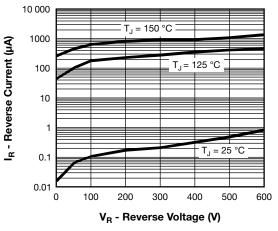
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C		
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.7			
Thermal resistance, junction-to-ambient	R _{thJA}	Typical socket mount	-	-	80	K/W		
Thermal resistance, case-to-heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	2.0	-	g		
weight			-	0.07	-	oz.		
Maulting dation		Case style D ² PAK (TO-263AB) HFA15TB605			TB60S			
Marking device		Case style TO-262AA	HFA15TB60-1					



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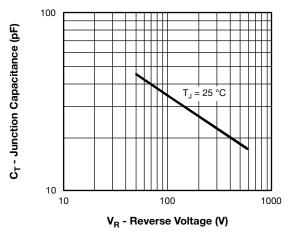
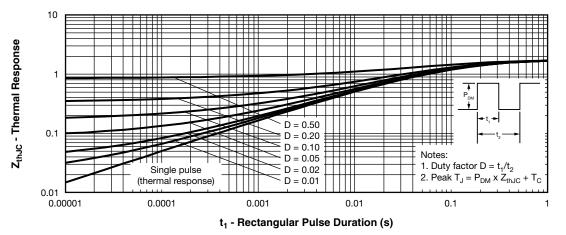
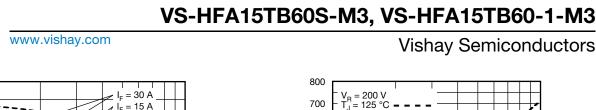


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage







= 25 °C T,

 $I_F = 30 A$

I_F = 15 A

 $I_{F} = 5 A$

600 500

400

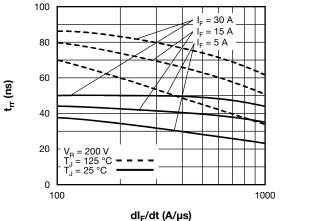
300 200

100

0

100

Q_{rr} (nC)



ISHA)

I_{rr} (A)

Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt

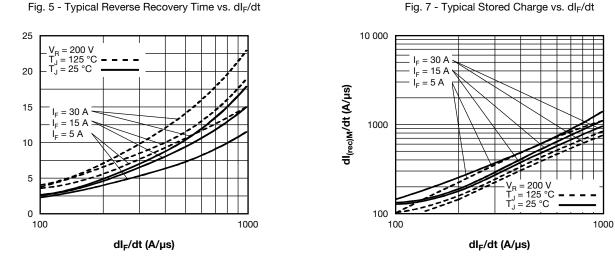
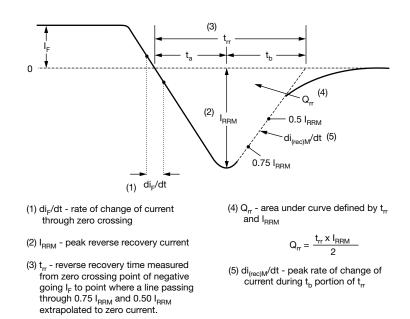


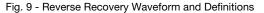
Fig. 6 - Typical Recovery Current vs. dl_F/dt



dl_F/dt (A/µs)

1000







Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	HF	Α	15	тв	60	S	L	-M3	
		2	3	4	5	6	7	8	9	
	1 ·		-	niconduc	ctors pro	oduct				
	2.		XFRED [©]	-						
			ctron irra	adiated ng (15 =	= 15 A)					
	5	- Pac	kage: = TO-22		1071					
	6		•	ng (60 = K (TO-2	,)				
	7		= TO-2							
	8 -	• N	one = tu	ıbe (50 p	oieces)					
									,	package)
	_	• R	= tape a	and reel	(right o	riented,	for D ² F	PAK (TC)-263AB	b) package
	9 -	M3	s = halog	gen-free	, RoHS	-complia	ant, and	termina	ations le	ad (Pb)-fr

ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER TUBE OR TAPE AND REEL		MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-HFA15TB60S-M3	50	1000	Antistatic plastic tube					
VS-HFA15TB60SL-M3	800	800	13" diameter reel					
VS-HFA15TB60SR-M3	800	800	13" diameter reel					
VS-HFA15TB60-1-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS						
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164				
Dimensions	TO-262AA	www.vishay.com/doc?96165				
Part marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444				
Part marking information	TO-262AA	www.vishay.com/doc?95443				
Packaging information		www.vishay.com/doc?96424				
SPICE model		www.vishay.com/doc?95357				

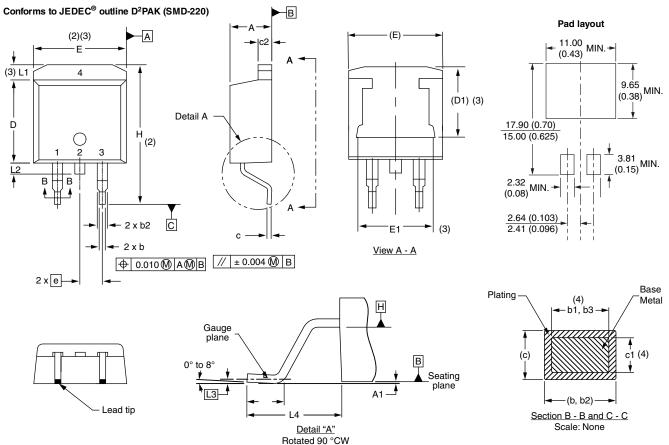
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D²PAK

DIMENSIONS in millimeters and inches

www.vishay.com

'ISHA'



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	MILLIMETERS		INCHES		
STINDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

.....

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

Controlling dimension: inches (6)

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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Document Number: 96164

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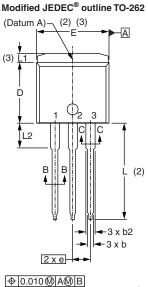
Outline Dimensions

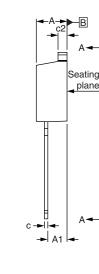


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TO-262AA

DIMENSIONS in millimeters and inches





D1 (3) (3) F1 Section A - A (4) Base Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None

F

0.010 🕅	AM B	



Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the state back. the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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